

Description

The SX80N06T uses advanced technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = 65V$ $I_D = 80A$

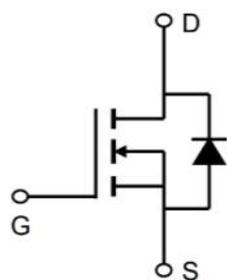
$R_{DS(ON)} < 8.0m\Omega @ V_{GS}=10V$

Application

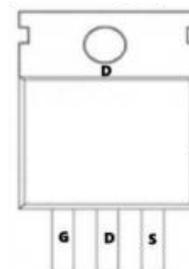
Battery protection

Load switch

Uninterruptible power supply



TO-263-3L



Absolute Maximum Ratings ($T_C=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Value	Unit
VDS	Drain source voltage	65	V
VGS	Gate source voltage	± 20	V
$I_D @ T_A=25^\circ C$	Continuous drain current	80	A
$I_D @ T_A=70^\circ C$	Continuous drain current	41	A
IDM	Pulsed drain current	240	A
$P_D @ T_A=25^\circ C$	Power dissipation	33.1	W
EAS	Single pulsed avalanche energy	130	mJ
TSTG	Storage Temperature Range	-55 to 150	$^\circ C$
Tj	Operation and storage temperature	-55 to 150	$^\circ C$
R θ JC	Thermal resistance, junction-case	2.1	$^\circ C/W$
R θ JA	Thermal resistance, junction-ambient5)	62.5	$^\circ C/W$

Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	65	72	-	V
IGSS	Gate-body Leakage Current	V _{DS} =0V, V _{GS} =±20V	-	-	±100	nA
IDSS T _J =25°C	Zero Gate Voltage Drain Current	V _{DS} =65V, V _{GS} =0V			1	μA
IDSS T _J =100°C					100	
VGS(th)	Gate-Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.2	1.7	2.5	V
RDS(on)	Drain-Source On-Resistance ⁴	V _{GS} =10V, I _D =20A	-	6.5	8.0	mΩ
RDS(on)	Drain-Source On-Resistance ⁴	V _{GS} =4.5V, I _D =10A		9.0	12	mΩ
gfs	Forward Transconductance ⁴	V _{DS} = 10V, I _D = 10A	-	45	-	S
Ciss	Input Capacitance	V _{DS} =30V, V _{GS} =0V, f =1MHz	-	1210	-	pF
Coss	Output Capacitance		-	343	-	
Crss	Reverse Transfer Capacitance		-	17	-	
R _g	Gate Resistance	f=1MHz	-	1.5	-	Ω
Q _g	Total Gate Charge	V _{GS} =10V, V _{DS} =30V, I _D = 10A	-	21.7	-	nC
Q _{gs}	Gate-Source Charge		-	3.9	-	
Q _{gd}	Gate-Drain Charge		-	4.5	-	
td(on)	Turn-On Delay Time	V _{GS} =10V, V _{DD} =30V, R _G = 3Ω, I _D =10A	-	7.3	-	ns
t _r	Rise Time		-	8.5	-	
td(off)	Turn-Off Delay Time		-	19.6	-	
t _f	Fall Time		-	5.6	-	
t _{rr}	Body Diode Reverse Recovery Time	I _F =10A, dI/dt=100A/μs	-	34	-	ns
Q _{rr}	Body Diode Reverse Recovery Charge		-	17	-	nC
VSD	Diode Forward Voltage ⁴	I _S =10A, V _{GS} = 0V	-	-	1.2	V
IS	Continuous Source Current	T _A =25°C	-	-	65	A

Note

- 1、 The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2、 The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3、 The EAS data shows Max. rating . The test condition is VDD=25V,VGS=10V,L=0.1mH,IAS=38A
- 4、 The power dissipation is limited by 150°C junction temperature
- 5、 The data is theoretically the same as ID and IDM , in real applications , should be limited by total power dissipation

Typical Characteristics

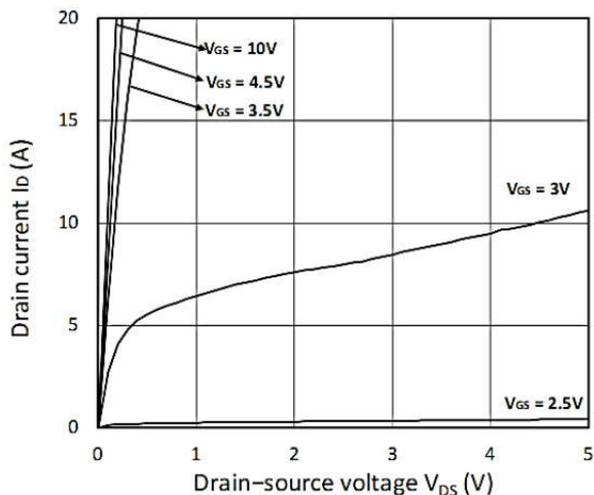


Figure 1. Output Characteristics

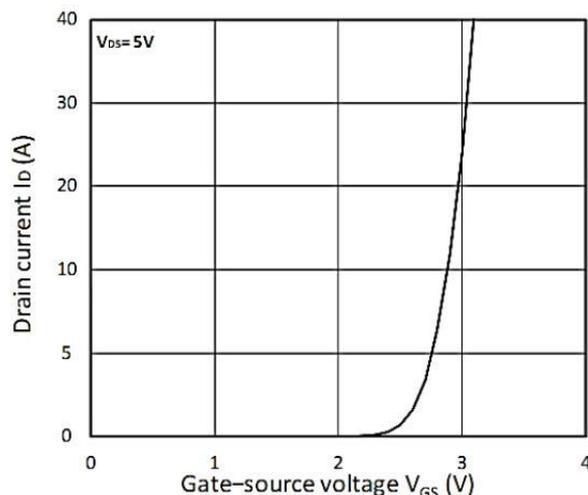


Figure 2. Transfer Characteristics

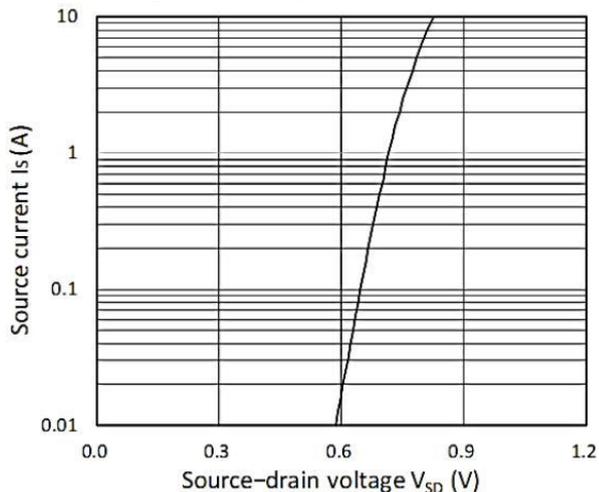


Figure 3. Forward Characteristics of Reverse

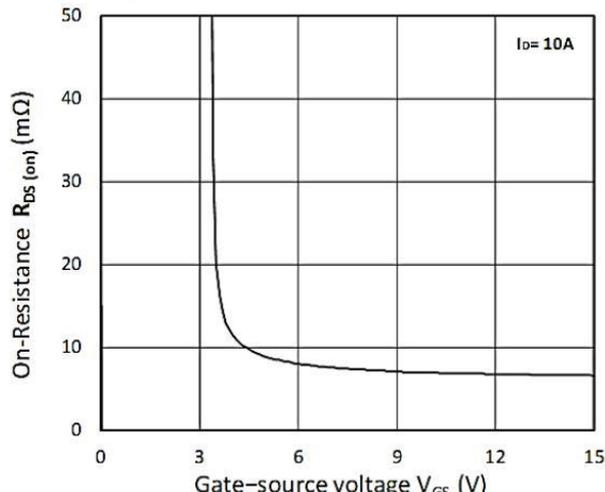


Figure 4. RDS(ON) vs. VGS

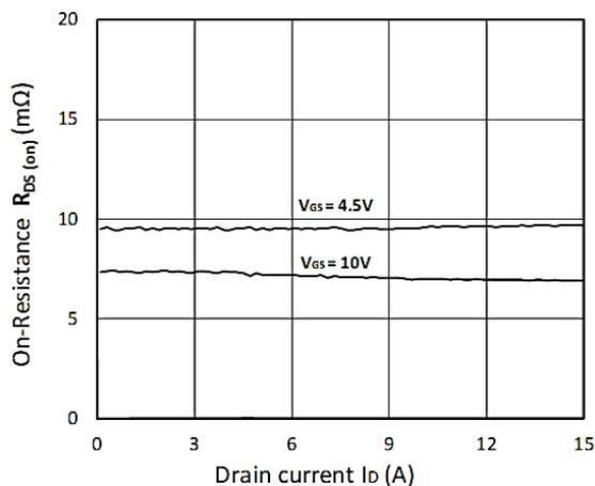


Figure 5. RDS(ON) vs. ID

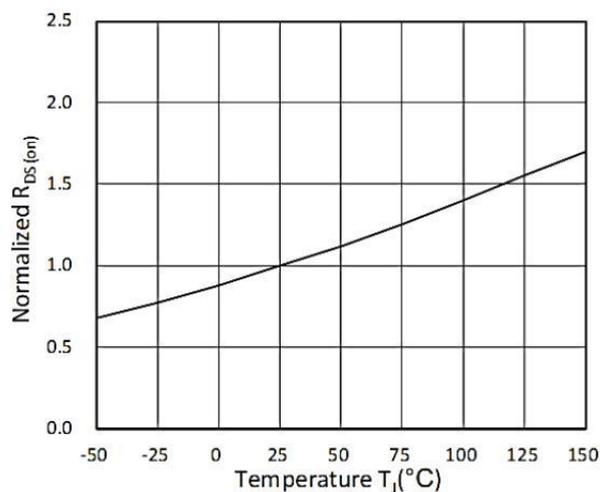


Figure 6. Normalized RDS(on) vs. Temperature

Typical Characteristics

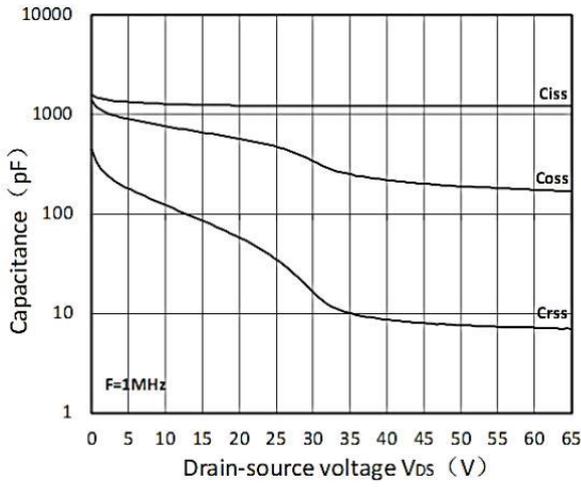


Figure 7. Capacitance Characteristics

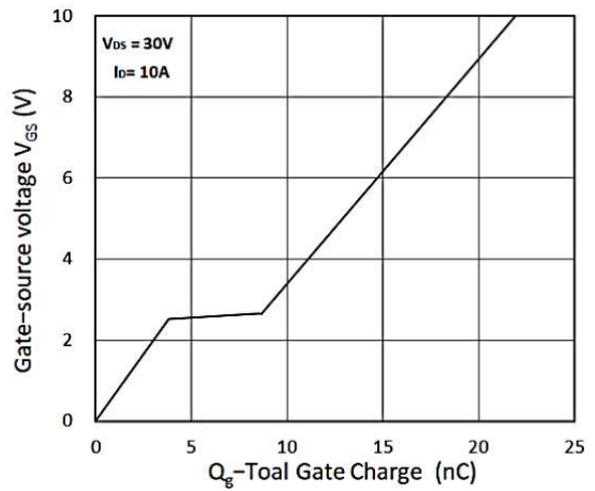


Figure 8. Gate Charge Characteristics

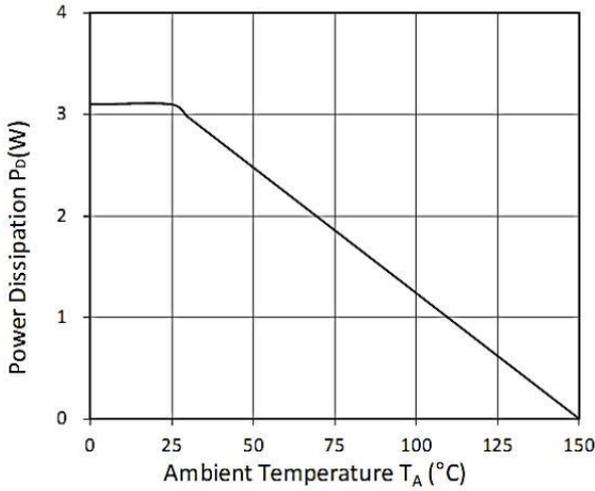


Figure 9. Power Dissipation

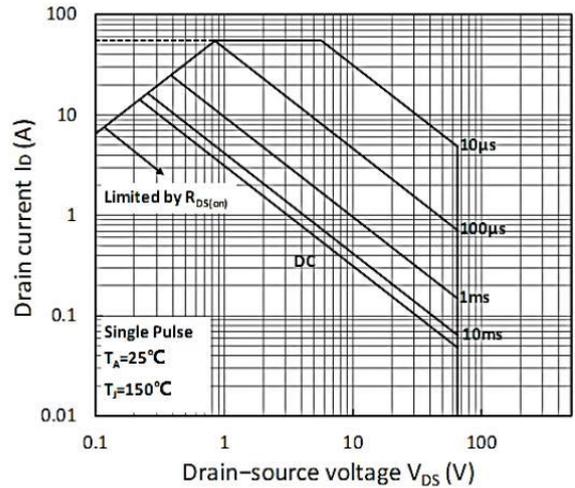


Figure 10. Safe Operating Area

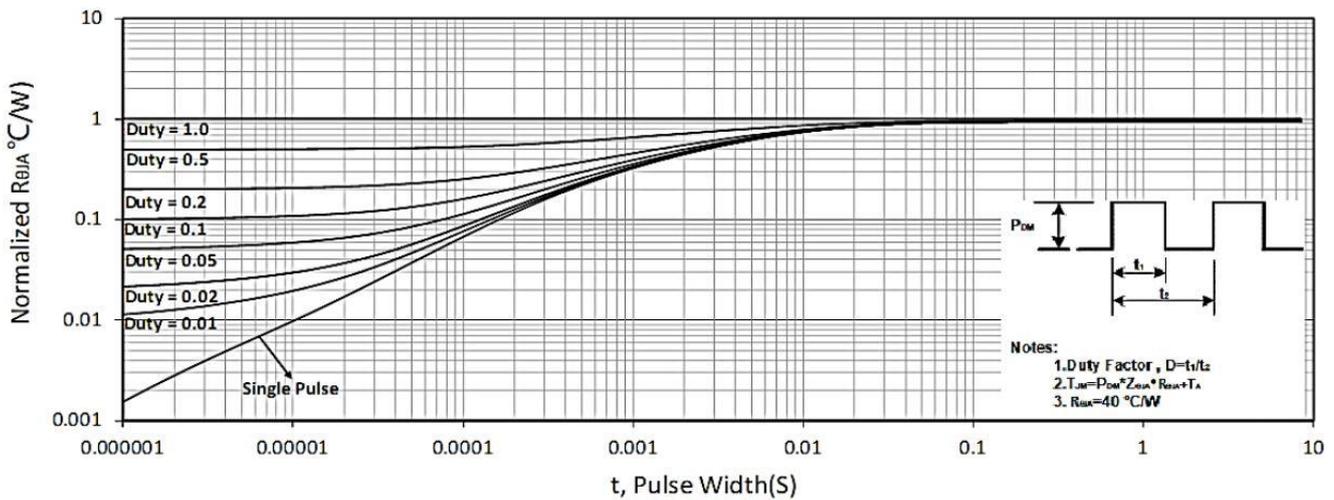
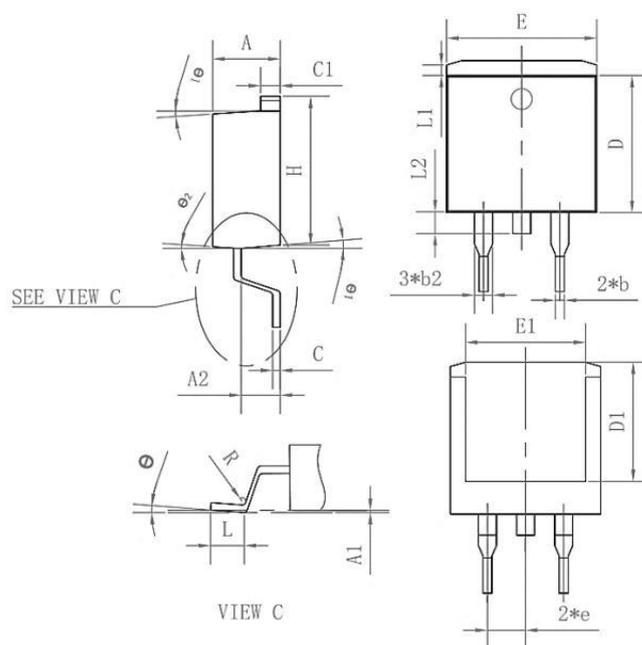


Figure 11. Normalized Maximum Transient Thermal Impedance

Package Mechanical Data-TO-263-3L-SLK


Symbol	Common		
	mm		
	Mim	Nom	Max
A	4.35	4.47	4.60
A1	0.09	0.10	0.11
A2	2.30	2.40	2.70
b	0.70	0.80	1.00
b2	1.25	1.36	1.50
C	0.45	0.50	0.65
C1	1.29	1.30	9.40
D	9.10	9.20	9.30
D1	7.90	8.00	8.10
E	9.85	10.00	10.20
E1	7.90	8.00	8.10
H	15.30	15.50	15.70
e	-	2.54	-
L	2.34	2.54	2.74
L1	1.00	1.10	1.20
L2	1.30	1.40	1.50
R	0.24	0.25	0.26
θ	0°	4°	8°
θ1	4°	7°	10°
θ2	0°	3°	6°

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	TO-263-3L		800